

## Wide-band, dual-path directional coupler with ISO port

### Features

- 50  $\Omega$  nominal input / output impedance
- Wide operating frequency range:
  - 824 MHz-2170 MHz
- Low insertion loss (< 0.2 dB)
- High directivity (> 20 dB)
- High ESD ruggedness
- Lead-free CSP package
- Small footprint: 1670 x 1440  $\mu\text{m}$
- Very low profile (< 650  $\mu\text{m}$  thickness)

### Benefits

- High RF performance
- RF module size reduction

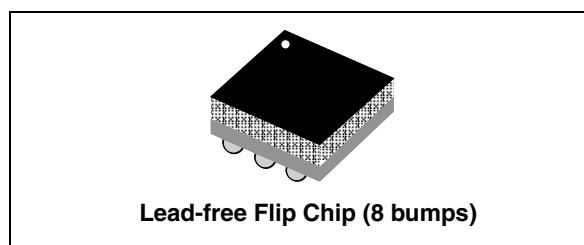
### Complies with the following standards:

- IEC 61000-4-2 level 4:
  - 15 kV (air discharge)
  - 8 kV (contact discharge)

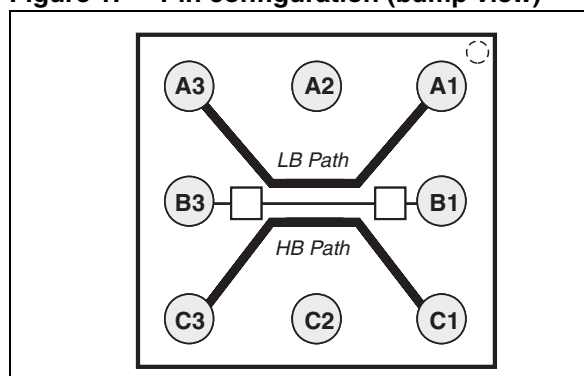
### Applications

Multi-band equipment such as:

- Power amplifier module
- Front end module
- GSM/WCDMA mobile phone



**Figure 1. Pin configuration (bump view)**



### Description

The DCPL-WB-00D3 is a wide-band, dual-path directional coupler designed to measure cell phone transmission output power in GSM/WCDMA applications. This dual path CPL has been customized for wide-band operating frequencies (EGSM and CELL, PCS, DCS, WCDMA band I) with less than 0.2 dB insertion losses in the transmission bandwidth (824 MHz - 1980 MHz).

This device is built with two different RF couplers (one dedicated to LB, the other dedicated to HB) sharing the same coupled and isolated ports. The DCPL-WB-00-D3 has been designed using STMicroelectronics IPD (integrated passive device) technology on non-conductive glass substrate to optimize RF performance.

The device is delivered 100% tested in tape and reel.

# 1 Characteristics

**Table 1. Device pin configuration**

| Bump | Name  | Description          |
|------|-------|----------------------|
| A1   | Lbin  | LB coupler RF input  |
| A2   | GND   | RF ground            |
| A3   | Lbout | LB coupler RF output |
| B1   | CPLD  | Coupler port         |
| B3   | ISO   | Isolated port        |
| C1   | Hbin  | HB coupler RF input  |
| C2   | GND   | RF ground            |
| C3   | Hbout | HB coupler output    |

**Table 2. Absolute maximum rating (limiting values)**

| Symbol          | Parameter                                                                                                                                                                                                                                                   | Value               |      |      | Unit |
|-----------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------|------|------|------|
|                 |                                                                                                                                                                                                                                                             | Min.                | Typ. | Max. |      |
| $P_{IN}$        | Input Power $RF_{IN}$ (CW mode)                                                                                                                                                                                                                             |                     |      | 35   | dBm  |
| $V_{ESD} (IEC)$ | ESD ratings IEC 61000-4-2 (C = 150 pF, R = 330 $\Omega$ )<br>LB <sub>IN</sub> , LB <sub>OUT</sub> , HB <sub>IN</sub> , HB <sub>OUT</sub> , air discharge<br>LB <sub>IN</sub> , LB <sub>OUT</sub> , HB <sub>IN</sub> , HB <sub>OUT</sub> , contact discharge | $\pm 15$<br>$\pm 8$ |      |      | kV   |
| $V_{ESD} (HBM)$ | Human body model, JESD 22-A114F, all I/O                                                                                                                                                                                                                    | 2                   |      |      | kV   |
| $V_{ESD} (MM)$  | Machine model, JESD 22-A115-A, all I/O                                                                                                                                                                                                                      | 100                 |      |      | V    |
| $V_{ESD} (CDM)$ | Charge device model, JESD 22-C101-C, all I/O                                                                                                                                                                                                                | 500                 |      |      | V    |
| $T_{OP}$        | Operating temperature                                                                                                                                                                                                                                       | -30                 |      | +85  | °C   |

**Table 3. Electrical characteristics - impedances ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )**

| Symbol    | Parameter                                  | Value |      |      | Unit     |
|-----------|--------------------------------------------|-------|------|------|----------|
|           |                                            | Min.  | Typ. | Max. |          |
| $Z_{OUT}$ | Nominal output impedance (LB and HB paths) |       | 50   |      | $\Omega$ |
| $Z_{IN}$  | Nominal input impedance (LB and HB paths)  |       | 50   |      | $\Omega$ |
| $Z_{CPL}$ | Nominal coupled port impedance             |       | 50   |      | $\Omega$ |
| $Z_{ISO}$ | Nominal isolated port impedance            |       | 50   |      | $\Omega$ |

**Table 4. Electrical characteristics - LB path RF performance ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )**

| Symbol               | Parameter                   | Test condition                       | Value |      |      | Unit |
|----------------------|-----------------------------|--------------------------------------|-------|------|------|------|
|                      |                             |                                      | Min.  | Typ. | Max. |      |
| f                    | Frequency range (bandwidth) |                                      | 824   |      | 960  | MHz  |
| IL <sub>LB</sub>     | LB path insertion loss      | From 824 MHz to 960 MHz              |       | 0.1  | 0.2  | dB   |
| RL <sub>LB</sub>     | LB path return loss         | From 824 MHz to 960 MHz              | 15    |      |      | dB   |
| CPLD <sub>LB</sub>   | LB path coupling factor     | From 824 MHz to 915 MHz              | 32    |      | 37   | dB   |
| Ripple <sub>LB</sub> | Coupling ripple in LB       | (824 to 849 MHz)<br>(880 to 915 MHz) |       |      | 0.5  | dB   |
| DIR <sub>LB</sub>    | LB coupler directivity      | From 824 MHz to 915 MHz              | 20    |      |      | dB   |

**Table 5. Electrical characteristics - HB path RF performance ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )**

| Symbol               | Parameter                   | Test condition                                                 | Value |      |      | Unit |
|----------------------|-----------------------------|----------------------------------------------------------------|-------|------|------|------|
|                      |                             |                                                                | Min.  | Typ. | Max. |      |
| f                    | Frequency range (bandwidth) |                                                                | 1710  |      | 1980 | MHz  |
| IL <sub>HB</sub>     | HB path insertion loss      | From 1710 MHz to 2170 MHz                                      |       | 0.1  | 0.2  | dB   |
| RL <sub>HB</sub>     | HB path return loss         | From 1710 MHz to 2170 MHz                                      | 15    |      |      | dB   |
| CPLD <sub>HB</sub>   | HB path coupling factor     | From 1710 MHz to 1980 MHz                                      | 29    |      | 34   | dB   |
| Ripple <sub>HB</sub> | Coupling ripple in HB       | (1710 to 1785 MHz)<br>(1850 to 1910 MHz)<br>(1920 to 1980 MHz) |       |      | 0.5  | dB   |
| DIR <sub>HB</sub>    | HB coupler directivity      | From 1710 MHz to 1980 MHz                                      | 20    |      |      | dB   |

# 1.1 RF measurement (on reference evaluation board)

Measurements done on reference evaluation board under 50  $\Omega$ , de-embedding at DCPL-WB-00D3 bumps.

Figure 2. Low band path insertion loss

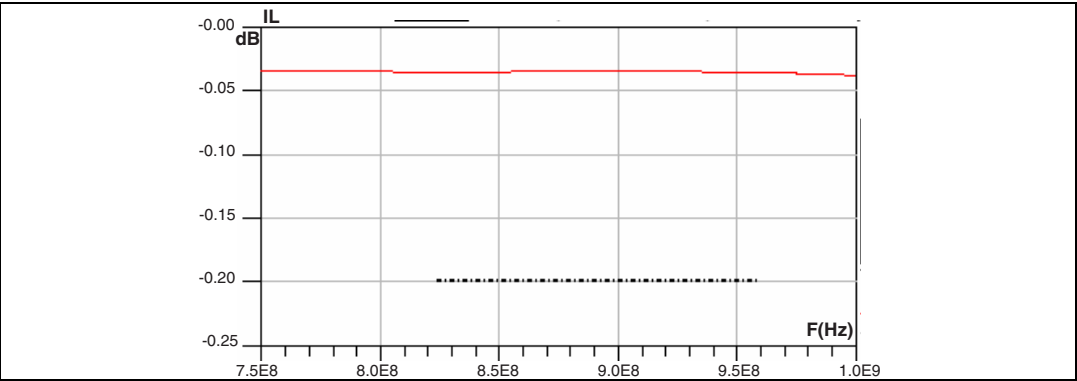


Figure 3. High band path insertion loss

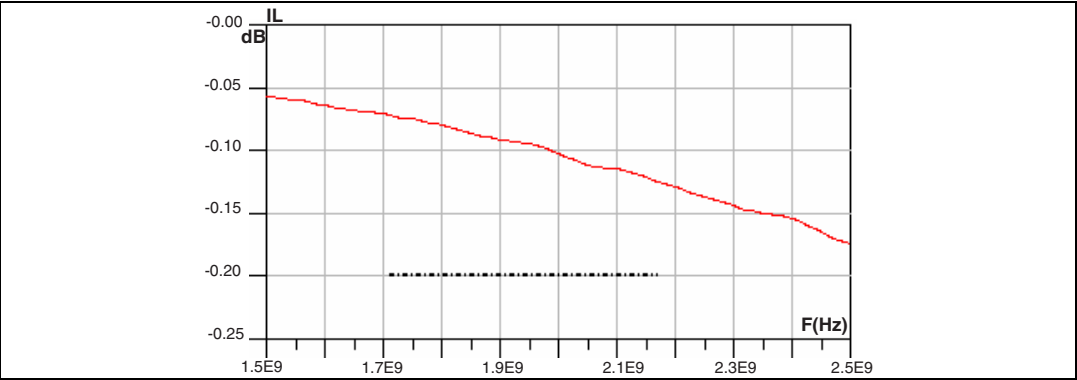


Figure 4. Low band path coupling factor

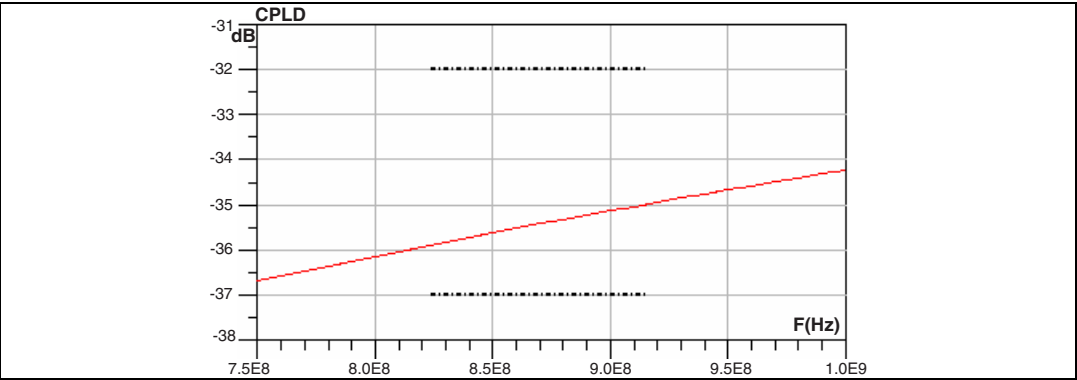


Figure 5. High band path coupling factor

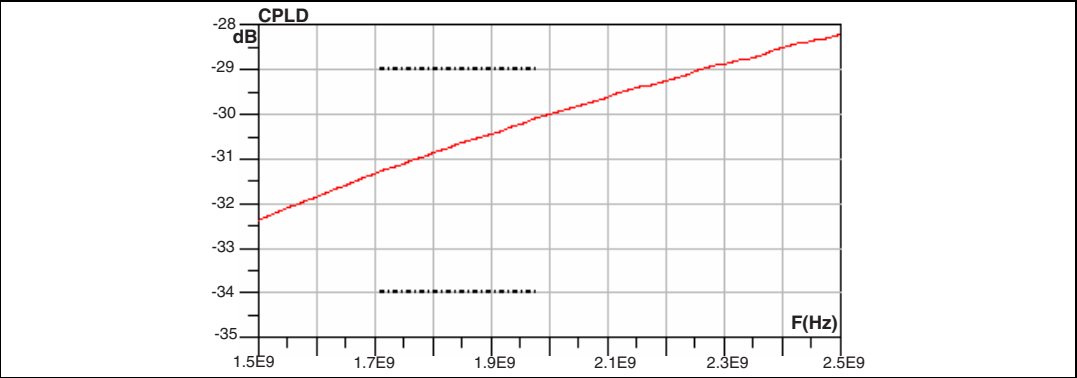


Figure 6. Low band path directivity

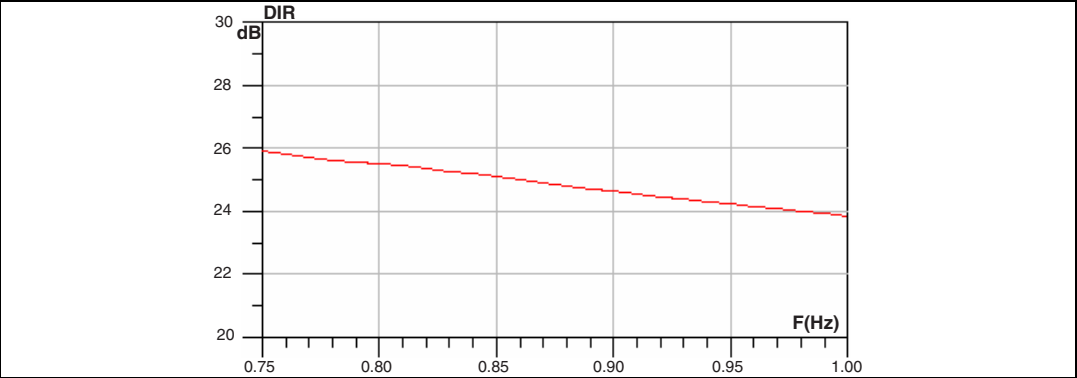
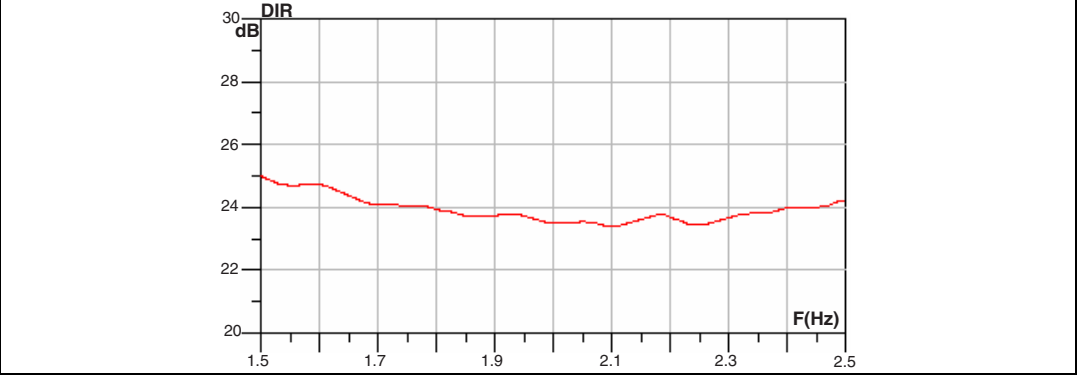
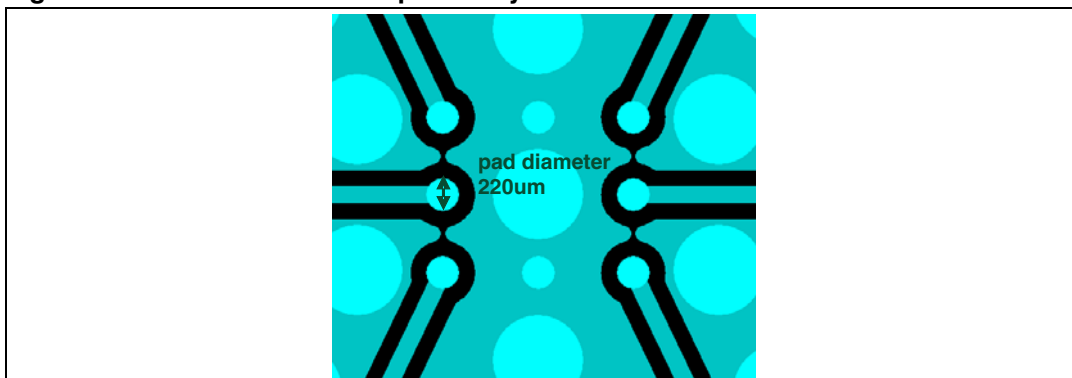
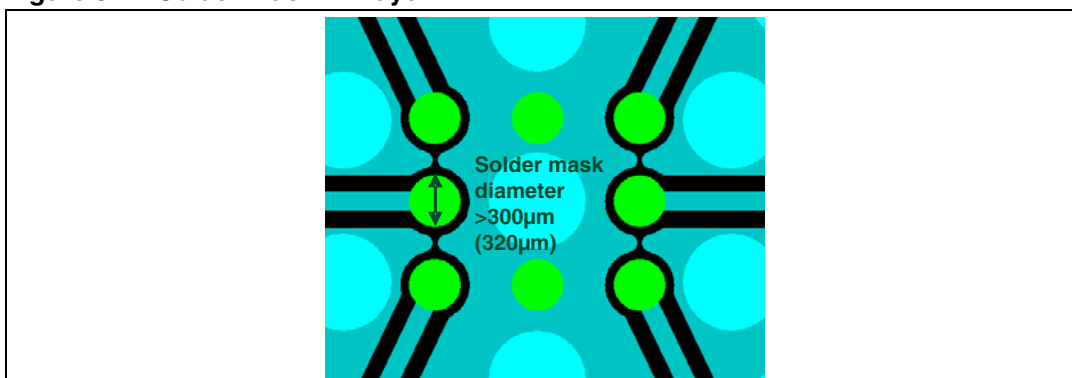


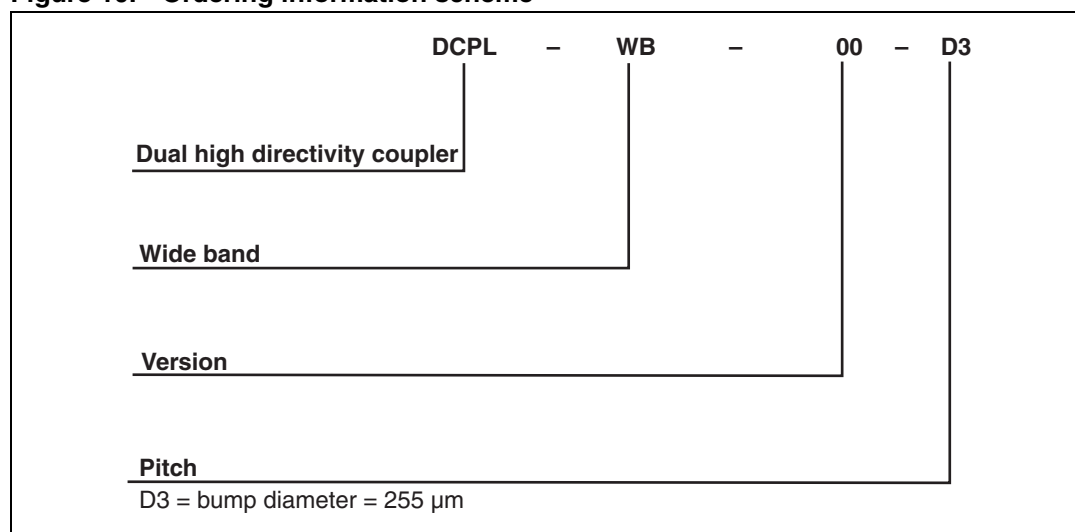
Figure 7. High band path directivity



**Figure 8. Demo board description - layer 1****Figure 9. Solder mask 1 + layer 1**

## 2 Ordering information scheme

Figure 10. Ordering information scheme



### 3 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

Figure 11. Package dimensions

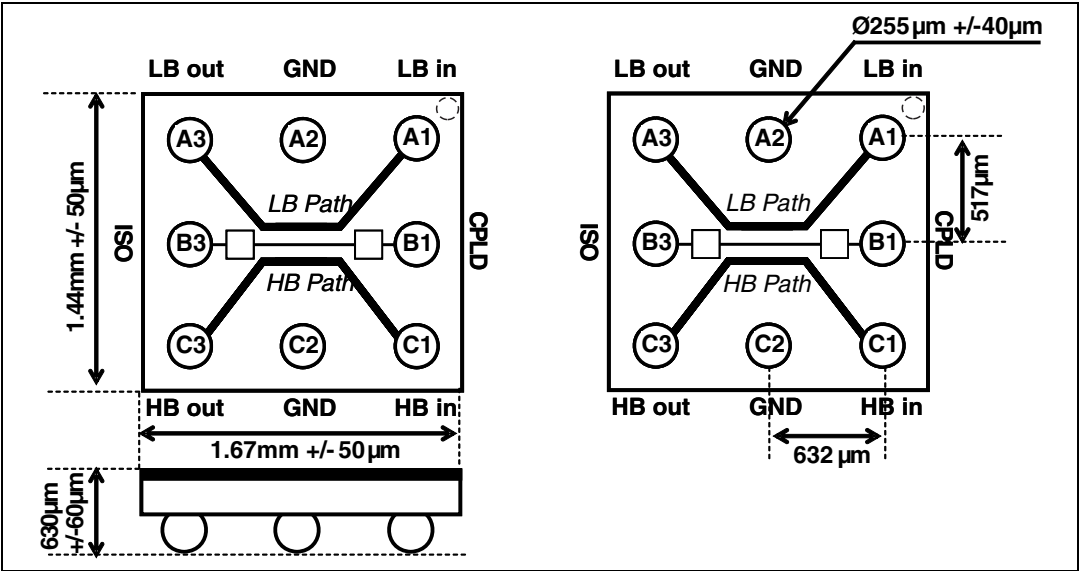


Figure 12. Footprint

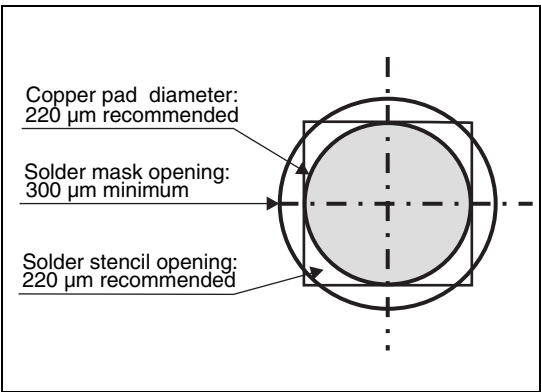


Figure 13. Marking

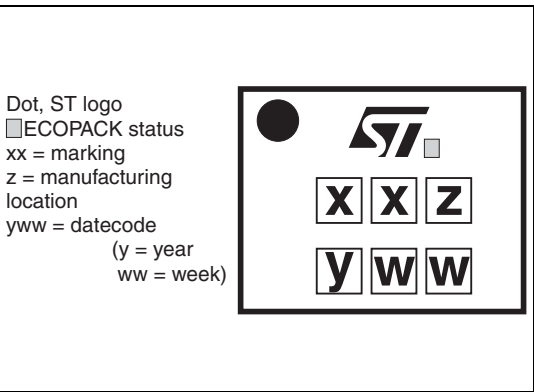
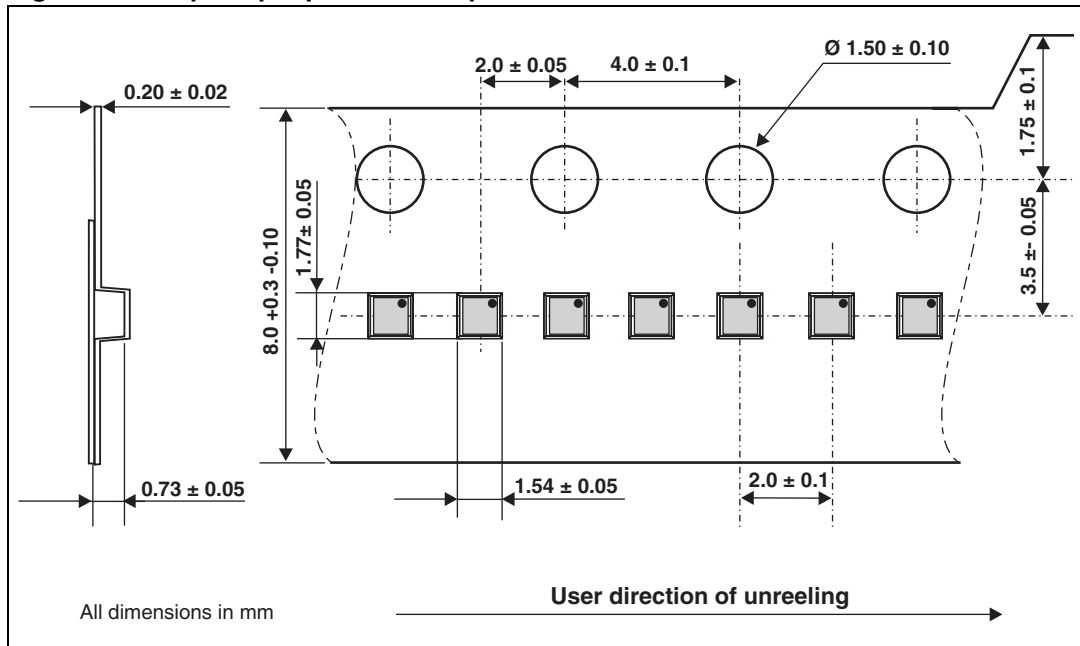


Figure 14. Flip-Chip tape and reel specifications



Note:

More packing information is available in the application notes:

AN2348: "400  $\mu$ m Flip-Chip: Package description and recommendations for use"

AN1751: "EMI Filters: Recommendations and measurements"

## 4 Ordering information

**Table 6. Ordering information**

| Order code   | Marking | Package   | Weight | Base qty | Delivery mode    |
|--------------|---------|-----------|--------|----------|------------------|
| DCPL-WB-00D3 | RS      | Flip Chip | 2.5 mg | 5000     | Tape and reel 7" |

## 5 Revision history

**Table 7. Document revision history**

| Date        | Revision | Changes         |
|-------------|----------|-----------------|
| 14-Apr-2010 | 1        | Initial release |

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